# MMBV105GLT1G

# **Silicon Tuning Diode**

This device is designed in the Surface Mount package for general frequency control and tuning applications. It provides solid-state reliability in replacement of mechanical tuning methods.

### Features

- Controlled and Uniform Tuning Ratio
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS (T<sub>C</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Voltage	V <sub>R</sub>	30	Vdc
Forward Current	١ <sub>F</sub>	200	mAdc
Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Junction Temperature	TJ	+125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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**CASE 318 STYLE 8** 

#### **MARKING DIAGRAM**



M4E = Specific Device Code Μ = Date Code\* .

= Pb-Free Package

(Note: Microdot may be in either location) \*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBV105GLT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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#### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Мах	Unit
Reverse Breakdown Voltage (I <sub>R</sub> = 10 μAdc)	V <sub>(BR)R</sub>	30	-	Vdc
Reverse Voltage Leakage Current (V <sub>R</sub> = 28 Vdc)	Ι <sub>R</sub>	_	50	nAdc

Device Type	С <sub>Т</sub> V <sub>R</sub> = 25 Vdc, f = 1.0 MHz pF		Q V <sub>R</sub> = 3.0 Vdc f = 50 MHz	C <sub>R</sub> C <sub>3</sub> /C <sub>25</sub> f = 1.0 MHz	
	Min	Мах	Тур	Min	Max
MMBV105GLT1	1.5	2.8	250	4.0	6.5

**TYPICAL CHARACTERISTICS** 

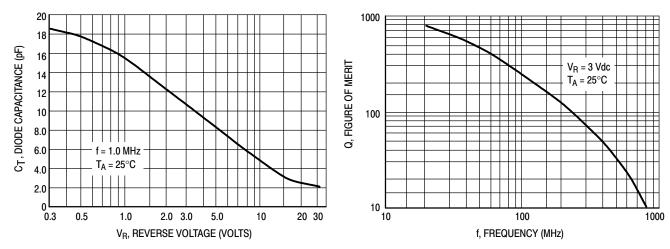


Figure 1. Diode Capacitance

Figure 2. Figure of Merit

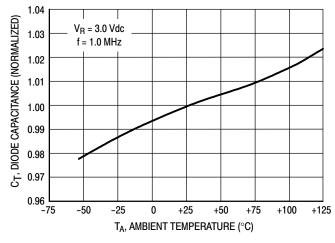


Figure 3. Diode Capacitance





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